**Product data sheet** 

# 1. Product profile

## 1.1 General description

Single high-speed switching diode, encapsulated in a SOD323F (SC-90) very small and flat lead Surface-Mounted Device (SMD) plastic package.

#### 1.2 Features

- High switching speed:  $t_{rr} \le 50$  ns
- Low leakage current
- Repetitive peak reverse voltage: V<sub>RRM</sub> ≤ 300 V
- Excellent coplanarity and improved thermal behavior
- Low capacitance: C<sub>d</sub> ≤ 2 pF
- Reverse voltage: V<sub>R</sub> ≤ 300 V
- Very small and flat lead SMD plastic package

## 1.3 Applications

- High-speed switching
- General-purpose switching
- Voltage clamping
- Reverse polarity protection

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>F</sub>	forward current		<u>[1]</u> -	-	250	mA
I <sub>R</sub>	reverse current	$V_{R} = 250 \text{ V}$	-	-	150	nA
$V_R$	reverse voltage		-	-	300	V
t <sub>rr</sub>	reverse recovery time		[2] _	-	50	ns

<sup>[1]</sup> Pulse test:  $t_0 \le 300 \,\mu\text{s}$ ;  $\delta \le 0.02$ .



<sup>[2]</sup> When switched from  $I_F$  = 30 mA to  $I_R$  = 30 mA;  $R_L$  = 100  $\Omega$ ; measured at  $I_R$  = 3 mA.

## Single high-speed switching diode

# 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Symbol
1	cathode	[1]	1.4
2	anode	1 2	+
			sym006

<sup>[1]</sup> The marking bar indicates the cathode.

# 3. Ordering information

Table 3. Ordering information

Type number	Package			
	Name	Description	Version	
BAS21J	SC-90	plastic surface-mounted package; 2 leads	SOD323F	

# 4. Marking

Table 4. Marking codes

Type number	Marking code
BAS21J	AN

### Single high-speed switching diode

# 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		• • •	,		
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage		-	300	V
$V_R$	reverse voltage		-	300	V
I <sub>F</sub>	forward current		<u>[1]</u> _	250	mA
I <sub>FRM</sub>	repetitive peak forward current	$t_p \leq 0.5 \text{ ms}; \\ \delta \leq 0.25$	-	1	Α
I <sub>FSM</sub>	non-repetitive peak forward current	square wave	[2]		
		$t_p = 100 \; \mu s$	-	3	Α
		$t_p = 1 \text{ ms}$	-	2.3	Α
		$t_p = 10 \text{ ms}$	-	1.7	А
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	[3][4]	550	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ .

## 6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2]	-	230	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		[3] -	-	55	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.

<sup>[2]</sup>  $T_i = 25$  °C prior to surge.

<sup>[3]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>

<sup>[4]</sup> Reflow soldering is the only recommended soldering method.

<sup>[2]</sup> Reflow soldering is the only recommended soldering method.

<sup>[3]</sup> Soldering point of cathode tab.

## Single high-speed switching diode

## 7. Characteristics

Table 7. Characteristics

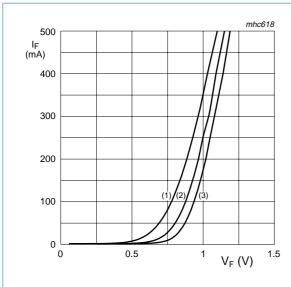
 $T_{amb} = 25 \,^{\circ}C$  unless otherwise specified.

	•					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{F}$	forward voltage	$I_F = 100 \text{ mA}$	<u>[1]</u> _	-	1.1	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 250 V	-	-	150	nA
		$V_R = 250 \text{ V}; T_j = 150 ^{\circ}\text{C}$	-	-	50	μΑ
$C_d$	diode capacitance	$V_R = 0 V$ ; $f = 1 MHz$	-	-	2	pF
t <sub>rr</sub>	reverse recovery time		[2] _	-	50	ns

<sup>[1]</sup> Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

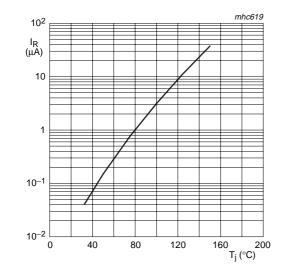
<sup>[2]</sup> When switched from I<sub>F</sub> = 30 mA to I<sub>R</sub> = 30 mA; R<sub>L</sub> = 100  $\Omega$ ; measured at I<sub>R</sub> = 3 mA.

### Single high-speed switching diode



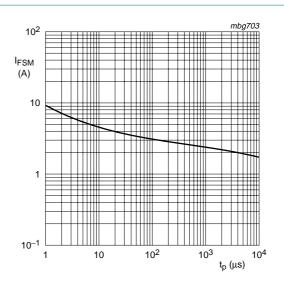
- (1)  $T_{amb} = 150 \, ^{\circ}C$
- (2)  $T_{amb} = 75 \,^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



 $V_{R} = 250 \text{ V}$ 

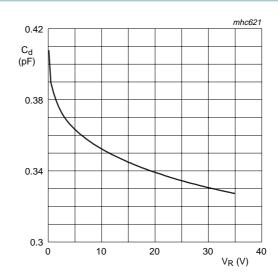
Fig 3. Reverse current as a function of junction temperature; typical values



Based on square wave currents.

 $T_i = 25$  °C; prior to surge

Fig 2. Non-repetitive peak forward current as a function of pulse duration; maximum values



 $f = 1 \text{ MHz}; T_{amb} = 25 \, ^{\circ}\text{C}$ 

Fig 4. Diode capacitance as a function of reverse voltage; typical values

## Single high-speed switching diode

# 8. Test information

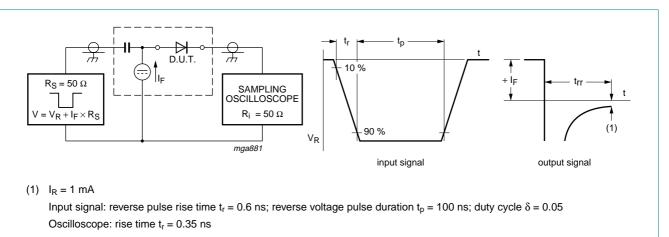
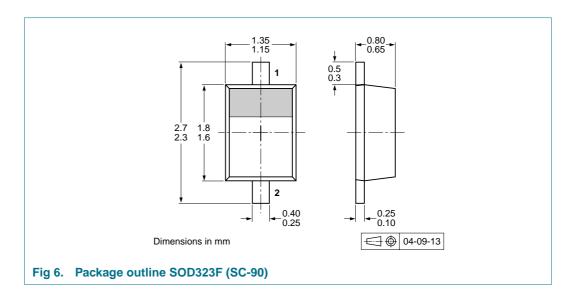


Fig 5. Reverse recovery time test circuit and waveforms

### Single high-speed switching diode

# 9. Package outline



# 10. Packing information

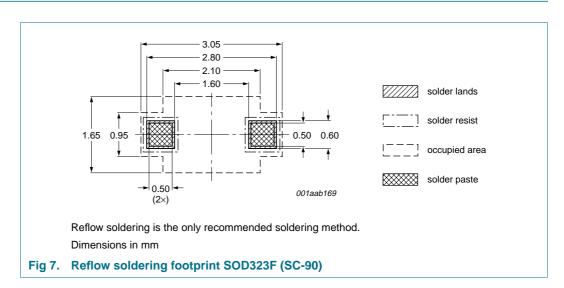
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing qu	antity
			3000	10000
BAS21J	SOD323F	4 mm pitch, 8 mm tape and reel	-115	-135

<sup>[1]</sup> For further information and the availability of packing methods, see Section 14.

# 11. Soldering



# Single high-speed switching diode

# 12. Revision history

## Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAS21J_1	20070308	Product data sheet	-	-

#### Single high-speed switching diode

## 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

#### 13.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

### 13.3 Disclaimers

**General** — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

**Suitability for use** — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or

malfunction of a NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nxp.com/profile/terms">http://www.nxp.com/profile/terms</a>, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by NXP Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

#### 13.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

#### 14. Contact information

For additional information, please visit: http://www.nxp.com

For sales office addresses, send an email to: <a href="mailto:salesaddresses@nxp.com">salesaddresses@nxp.com</a>

BAS21J\_1 © NXP B.V. 2007. All rights reserved.

### Single high-speed switching diode

# 15. Contents

1	Product profile
1.1	General description
1.2	Features
1.3	Applications
1.4	Quick reference data
2	Pinning information 2
3	Ordering information 2
4	Marking 2
5	Limiting values 3
6	Thermal characteristics 3
7	Characteristics 4
8	Test information 6
9	Package outline 7
10	Packing information 7
11	Soldering 7
12	Revision history 8
13	Legal information 9
13.1	Data sheet status 9
13.2	Definitions
13.3	Disclaimers
13.4	Trademarks 9
14	Contact information 9
15	Contents

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

